

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
1	BRS	L8	145220	capacitor and contain\$5	USPAT; US-PGP; UB; EPO; JPO; DERWE NT; IBM_TD B	2002/12/04 17:00			0
2	BRS	L15	33369	8 and (silicon or polysilicon)	USPAT; US-PGP; UB; EPO; JPO; DERWE NT; IBM_TD B	2002/12/04 17:02			0
3	BRS	L22	27020	15 and (dop\$5 or undop\$5 or heavy or lightly or less)	USPAT; US-PGP; UB; EPO; JPO; DERWE NT; IBM_TD B	2002/12/04 17:03			0
4	BRS	L29	26758	22 and (inner or outer or peripher\$5 or first or second or layer)	USPAT; US-PGP; UB; EPO; JPO; DERWE NT; IBM_TD B	2002/12/04 17:07			0
5	BRS	L36	612	29 and (HSG or (hemispherical adj1 grain adj1 silicon))	USPAT; US-PGP; UB; EPO; JPO; DERWE NT; IBM_TD B	2002/12/04 17:08			0
6	BRS	L43	611	36 and (dielectric or top or plate or conductive or electrode)	USPAT; US-PGP; UB; EPO; JPO; DERWE NT; IBM_TD B	2002/12/04 17:11			0
7	BRS	L50	2242	("438/253") or ("438/398") or ("438/255") or ("438/253") or ("438/964").cdls.	USPAT; US-PGP; UB; EPO; JPO; DERWE NT; IBM_TD B	2002/12/04 17:12			0
8	BRS	L57	279	43 and 50	USPAT; US-PGP; UB; EPO; JPO; DERWE NT; IBM_TD B	2002/12/04 17:12			0
9	BRS	L64	536	43 and (vacuum or temperature or heat or degrees or torr or minutes or silane or gas or "550")	USPAT; US-PGP; UB; EPO; JPO; DERWE NT; IBM_TD B	2002/12/04 17:14			0
10	BRS	L71	333	64 and (anneal\$5)	USPAT; US-PGP; UB; EPO; JPO; DERWE NT; IBM_TD B	2002/12/04 17:15			0
11	BRS	L92	177	71 and 50	USPAT; US-PGP; UB; EPO; JPO; DERWE NT; IBM_TD B	2002/12/04 17:16			0